

BoT-nLE521

Specification

CONFIDENTIAL INFORMATION

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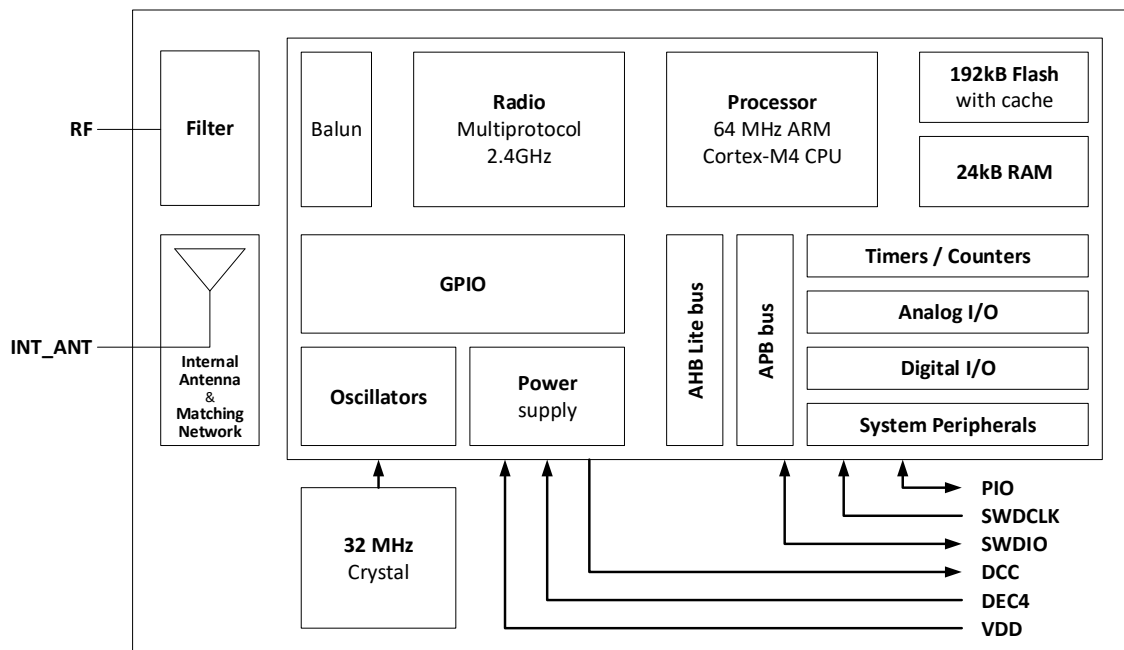
1. General

1.1 Overview

The BoT-nLE521 module is a cost-effective, low-power, true system-on-chip (SoC) for Bluetooth Smart (Bluetooth low energy) applications. It enables robust BLE master or slave nodes to be built with very low total bill-of-material costs. BoT-nLE521 combines an excellent RF transceiver with an industry-standard enhanced Cortex-M4 CPU, in-system programmable flash memory, 24kB RAM, and many other powerful supporting features and peripherals. The BoT-nLE521 is suitable for systems where very low power

Consumption is required. Very low-power sleep modes are available. Short transition times between operating modes further enable low power consumption.

1.2 Block Diagram



BoT-nLE521 Block Diagram

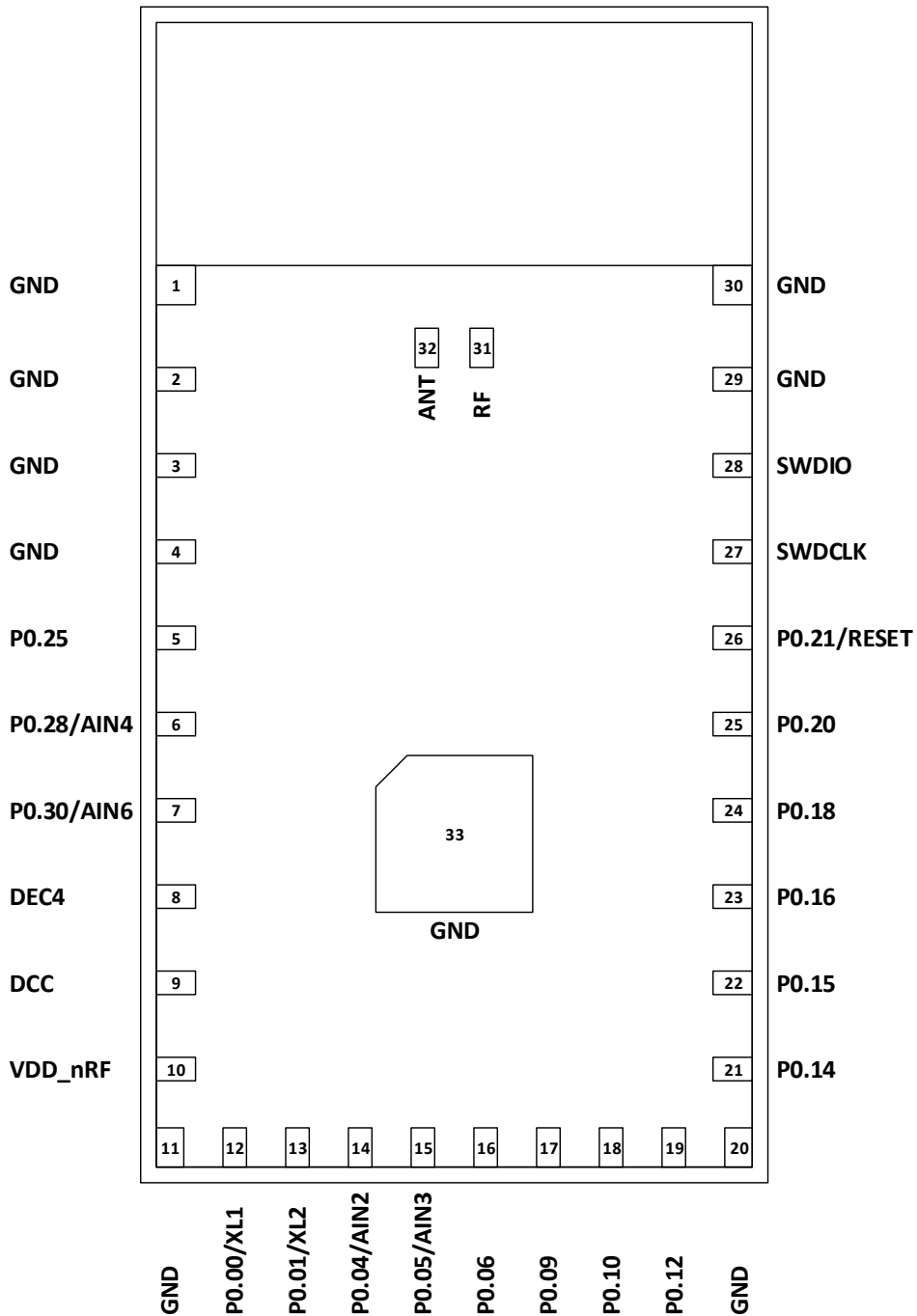
1.3 Features

- Built in Antenna Bluetooth Smart (Bluetooth Low Energy) Module.
- ARM® Cortex®-M4 32-bit processor with FPU, 64 MHz
- Memory: 192 kB Flash / 24 kB RAM
- RF Output Power: MAX +4 dBm (-20 ~ 4 dBm)
- RF Receive Sensitivity: -96 dBm
- Type 2 near field communication (NFC-A) tag with wakeup-on-field and touch to-pair capabilities
- Fully automatic LDO and DC/DC regulator system (Used LDO by Default)
- Temperature Sensor
- UART (CTS/RTS) with EasyDMA, SPI, and I2C data interfaces.
- 12-Bit 200 ksp/s ADC with - 8 configurable channels with programmable gain
- Size: 15 mm x 8 mm x 1.8 mm
- Operating Voltage: 1.7V to 3.6V
- Operating Temperature: -40 to +85°C
- RoHS compliant

1.4 Application

- Computer peripherals and I/O devices
 - Mouse
 - Keyboard
 - Multi-touch trackpad
- Interactive entertainment devices
- Remote control
 - Gaming controller
- Beacons
- Personal Area Networks
 - Health/fitness sensor and monitor devices
 - Medical devices
 - Key-fobs + wrist watches
- Remote control toys

1.5 Pin Configuration

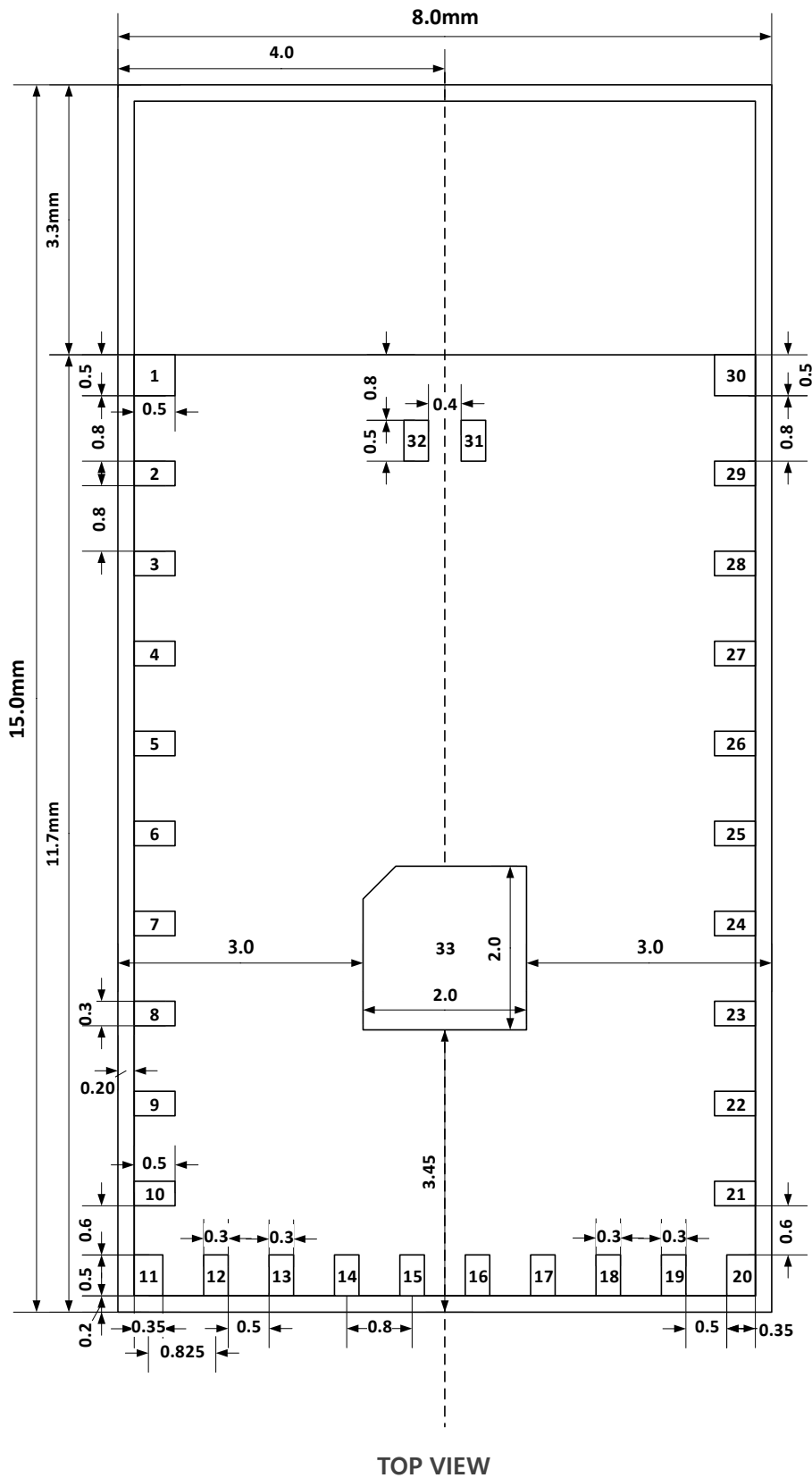


TOP VIEW

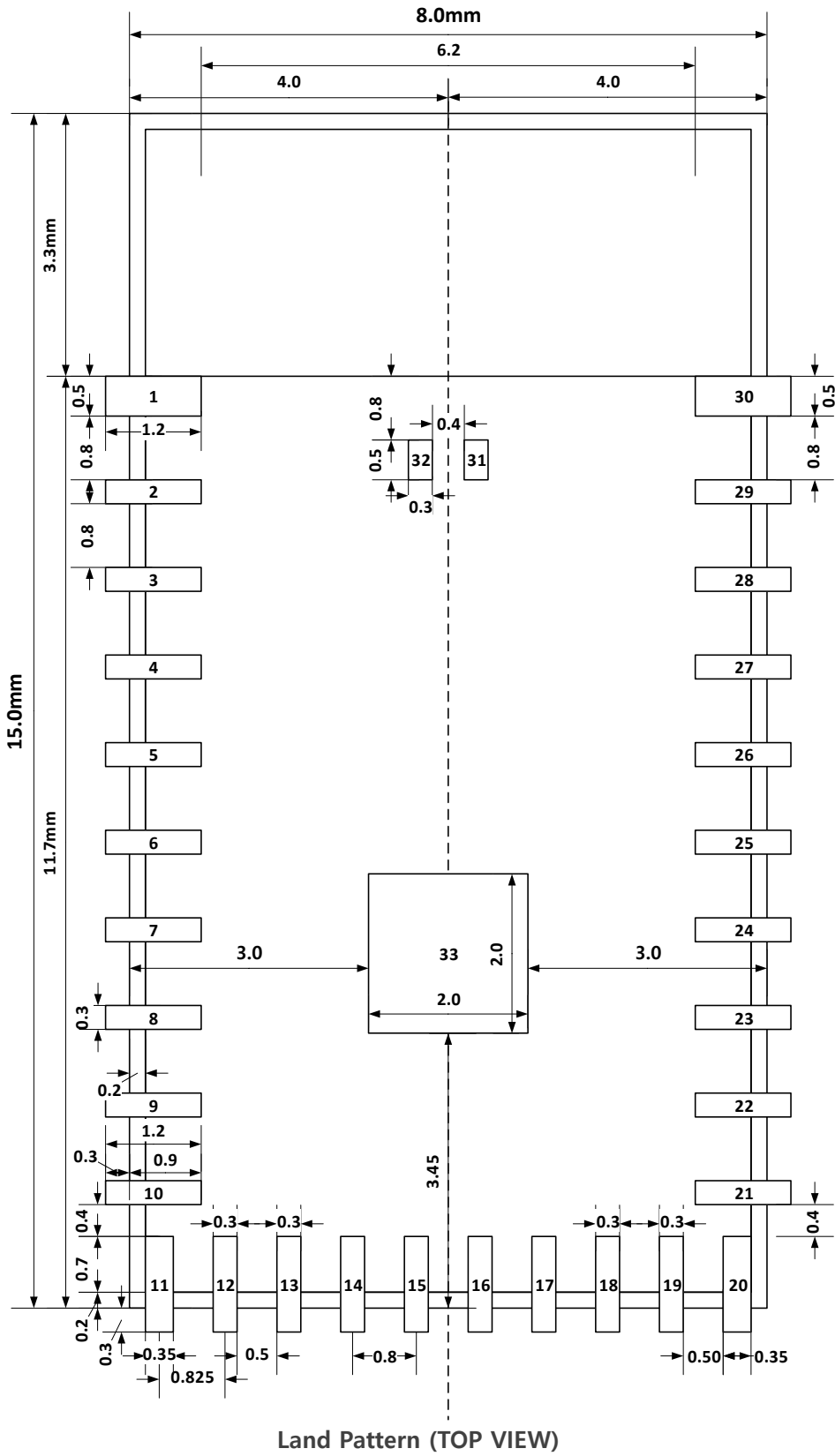
1.6 PIN Description

Pin No.	Pin Name	Pin Function	Description
01	GND	GROUND	Ground Pin.
02	GND	GROUND	Ground Pin.
03	GND	GROUND	Ground Pin.
04	GND	GROUND	Ground Pin.
05	P0.25	DIGITAL I/O	General purpose I/O pin.
06	P0.28	DIGITAL I/O	General purpose I/O pin.
	AIN4	ANALOG INPUT	SAADC/COMP input
07	P0.30	DIGITAL I/O	General purpose I/O pin.
	AIN6	ANALOG INPUT	COMP input
08	DEC4	POWER	1.3 V regulator supply decoupling Input from DC/DC converter. Output from 1.3 V LDO
09	DCC	POWER	DC/DC regulator output
10	VDD_nRF	POWER	Power supply pin.
11	GND	GROUND	Ground Pin.
12	P0.00	DIGITAL I/O	General purpose I/O pin.
	XL1	ANALOG INPUT	Connection for 32.768 kHz crystal (LFXO)
13	P0.01	DIGITAL I/O	General purpose I/O pin.
	XL2	ANALOG INPUT	Connection for 32.768 kHz crystal (LFXO)
14	P0.04	DIGITAL I/O	General purpose I/O pin.
	AIN2	ANALOG INPUT	SAADC/COMP input
	CTS	DIGITAL OUTPUT	UART CTS
15	P0.05	DIGITAL I/O	General purpose I/O pin.
	AIN3	ANALOG INPUT	SAADC/COMP input
	RTS	DIGITAL INPUT	UART RTS
16	P0.06	DIGITAL I/O	General purpose I/O pin.
	RXD	DIGITAL INPUT	UART RXD
17	P0.09	DIGITAL I/O	General purpose I/O pin.
	TXD	DIGITAL OUTPUT	UART TXD
18	P0.10	DIGITAL I/O	General purpose I/O pin.
	DISCONNECT & FACTORY_RST	DIGITAL INPUT	DISCONNECT & FACTORY_RESET
19	P0.12	DIGITAL I/O	General purpose I/O pin.
	ENTER_SLEEP / WAKE_UP	DIGITAL INPUT	ENTER_SLEEP / WAKE_UP
20	GND	GROUND	Ground Pin.
21	P0.14	DIGITAL I/O	General purpose I/O pin.
22	P0.15	DIGITAL I/O	General purpose I/O pin.
23	P0.16	DIGITAL I/O	General purpose I/O pin.
24	P0.18	DIGITAL I/O	General purpose I/O pin.
	AT COMMAND / BYPASS	DIGITAL INPUT	AT COMMAND/BYPASS
25	P0.20	DIGITAL I/O	General purpose I/O pin.
	CONNECTION STATUS	DIGITAL OUTPUT	CONNECTION STATUS
26	P0.21	DIGITAL I/O	General purpose I/O pin.
	RESET	nRESET	Configurable as system RESET pin.
27	SWDCLK	DIGITAL INPUT	Serial Wire Debug clock input for debug and programming
28	SWDIO	DIGITAL I/O	Serial Wire Debug I/O for debug and programming
29	GND	GROUND	Ground Pin.
30	GND	GROUND	Ground Pin.
31	RF	RF IN / OUT PORT	Bluetooth 50Ω transmitter output / receiver input
32	ANT	INTERNAL ANTENNA IN / OUT	Internal antenna. It should be connected to Pin 32 RF for normal operation.
33	GND	GROUND	Ground Pin.

1.7 Dimensions



1.8 Land Pattern



2. Characteristics

2.1 Electrical Characteristics

▪ Absolute Maximum Ratings

Symbol	Parameter	Min.	Max.	Units
VDD		-0.3	+3.9	V
GND			0	V
V _{I/O} , VDD ≤ 3.6V		-0.3	VDD + 0.3	V
V _{I/O} , VDD > 3.6V		-0.3	+3.9	V
Storage temperature		-40	+125	°C
Radio	RF Input Level		10	dBm
MSL	Moisture Sensitivity Level	2		
ESD HBM	Human Body Model		4	kV
ESD CDM	Charged Device Model		1000	V
Endurance	Flash Memory Endurance	10000		write/erase cycles
Retention	Flash Memory Retention	10 years		At 40 °C

▪ Recommended Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Units
VDD	LDO Regulator Operation (Default Mode)	1.7	3.0	3.6	V
VDD	DC/DC Regulator Operation	2.1	3.0	3.6	V
t _r _VDD	Supply rise time (0V to 1.7V)			60	ms
TA	Operation temperature	-40	25	85	°C

▪ DC Characteristics

Symbol	Parameter (condition)	Min.	Typ.	Max.	Units
V _{IH}	Input high voltage	0.7 X VDD		VDD	V
V _{IL}	Input low voltage	VSS		0.3 X VDD	V
V _{OH,SD}	Output high voltage, standard drive, 0.5 mA, VDD ≥ 1.7	VDD-0.4		VDD	V
V _{OH,HDL}	Output high voltage, high drive, 5 mA, VDD ≥ 2.7 V	VDD-0.4		VDD	V
V _{OH,HDL}	Output high voltage, high drive, 3 mA, VDD ≥ 1.7 V	VDD-0.4		VDD	V
V _{OL,SD}	Output low voltage, standard drive, 0.5 mA, VDD ≥ 1.7	VSS		VSS + 0.4	V
V _{OL,HDL}	Output low voltage, high drive, 5 mA, VDD ≥ 2.7 V	VSS		VSS + 0.4	V

V _{OL,HDL}	Output low voltage, high drive, 3 mA, VDD ≥ 1.7 V	VSS		VSS +0.4	V
R _{PU}	Pull-up resistance	11	13	16	kΩ
R _{PD}	Pull-down resistance	11	13	16	kΩ
I _{TX,+4dBm,DCDC}	TX only run current (DCDC, 3V) P _{RF} =+4 dBm		7.0		mA
I _{TX,+4dBm}	TX only run current P _{RF} =+4 dBm		15.4		mA
I _{RX,1M,DCDC}	RX only run current (DCDC, 3V) 1Msps		4.6		mA
I _{RX,1M}	RX only run current 1Msps		10.0		mA
I _{RX,2M,DCDC}	RX only run current (DCDC, 3V) 2Msps		5.2		mA
I _{RX,2M}	RX only run current 2Msps		11.2		mA
I _{ON_RAMOFF_EVENT}	System ON, No RAM retention, Wake on any event		0.6		μA
I _{ON_RAMON_EVENT}	System ON, Full 24 kB RAM retention, Wake on any event		0.8		μA
I _{ON_RAMON_POF}	System ON, Full 24 kB RAM retention, Wake on any event, Power fail comparator enabled		0.8		μA
I _{ON_RAMON_GPIOTE}	System ON, Full 24 kB RAM retention, Wake on GPIOTE input (Event mode)		3.3		μA
I _{ON_RAMON_GPIOTEPORT}	System ON, Full 24 kB RAM retention, Wake on GPIOTE PORT event		0.8		μA
I _{ON_RAMON_RTC}	System ON, Full 24 kB RAM retention, Wake on RTC (running from LFRC clock)		1.5		μA
I _{OFF_RAMOFF_RESET}	System OFF, No RAM retention, Wake on reset		0.3		μA
I _{OFF_RAMON_RESET}	System OFF, Full 24 kB RAM retention, Wake on reset		0.5		μA

2.2 RF Characteristics

Symbol	Description	Min.	Typ.	Max.	Units
f_{OP}	Operating frequencies	2402		2480	MHz
$f_{PLL,PROG,RES}$	PLL programming resolution		2		kHz
$f_{PLL,CH,SP}$	PLL channel spacing		1		MHz
$f_{DELTA,BLE,1M}$	Frequency deviation @ BLE 1Msps		± 250		kHz
$f_{DELTA,BLE,2M}$	Frequency deviation @ BLE 2Msps		± 500		kHz
P_{RF}	Maximum output power		0	4	dBm
P_{RFC}	RF power control range		24		dB
P_{RFCR}	RF power accuracy			± 4	dB
$P_{RF1,1}$	1st Adjacent Channel Transmit Power 1 MHz (1 Msps)		-25		dBc
$P_{RF2,1}$	2nd Adjacent Channel Transmit Power 2 MHz (1 Msps)		-50		dBc
$P_{RF1,2}$	1st Adjacent Channel Transmit Power 2 MHz (2 Msps)		-25		dBc
$P_{RF2,2}$	2nd Adjacent Channel Transmit Power 4 MHz (2 Msps)		-50		dBc
$P_{RX,MAX}$	Maximum received signal strength at < 0.1% PER		0		dBm
$P_{SENS,IT,SP,1M,BLE}$	Sensitivity, 1Msps BLE ideal transmitter, ≤ 37 bytes BER=1E-3		-96		dBm
$P_{SENS,IT,SP,2M,BLE}$	Sensitivity, 2Msps BLE ideal transmitter, ≤ 37 bytes		-93		dBm
$RSSI_{ACC}$	RSSI Accuracy Valid range -90 to -20 dBm		± 2		dB
$RSSI_{RESOLUTION}$	RSSI resolution		1		dB
$RSSI_{PERIOD}$	Sample period		8		us

3. Terminal Description

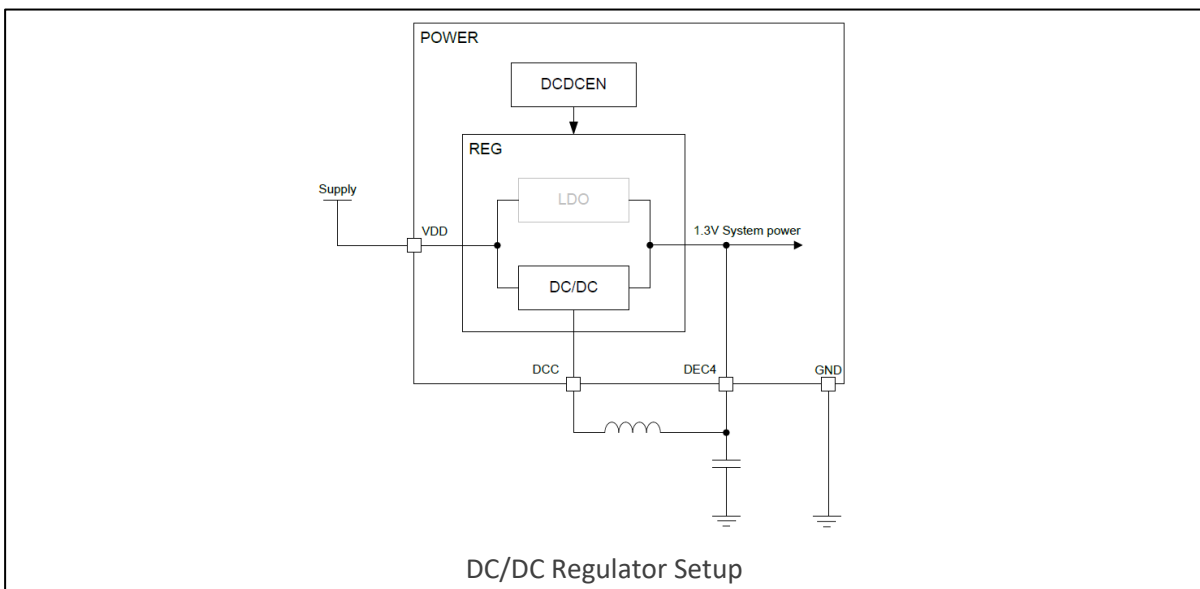
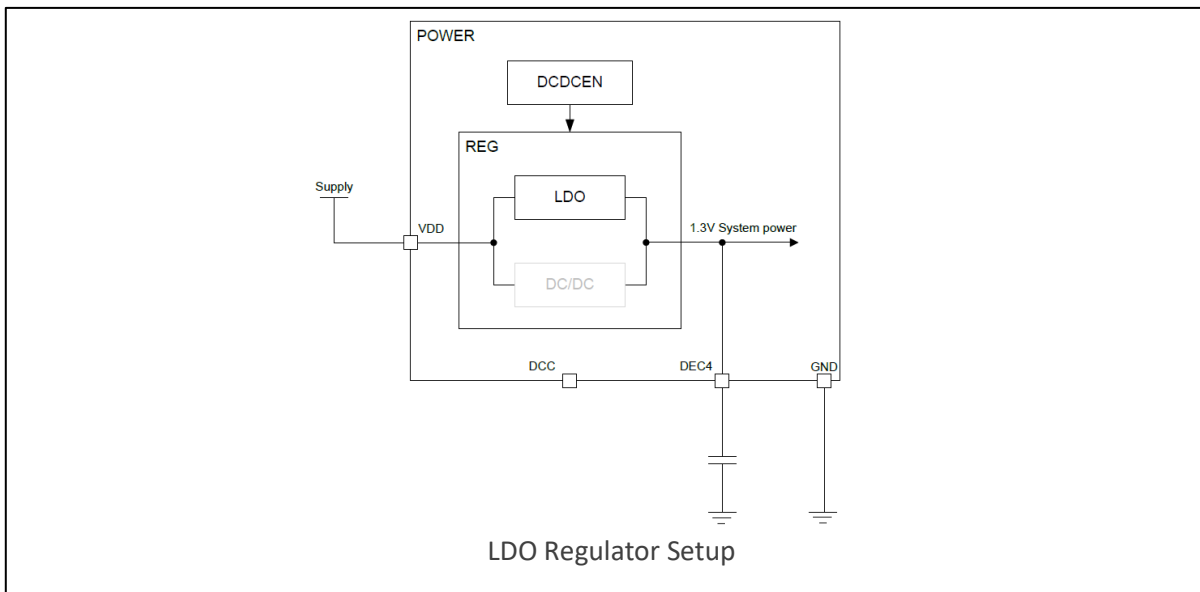
3.1 Regulator

The following internal power regulator alternatives are supported:

- Internal LDO regulator
- Internal DC/DC regulator

The LDO is the default regulator.

Using the DC/DC regulator will reduce current consumption compared to when using the LDO regulator, but the DC/DC regulator requires an external LC filter to be connected, as shown in Figure.



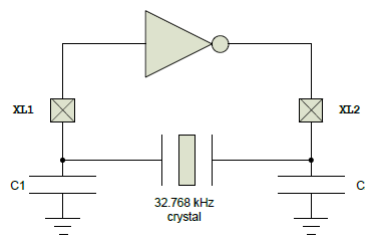
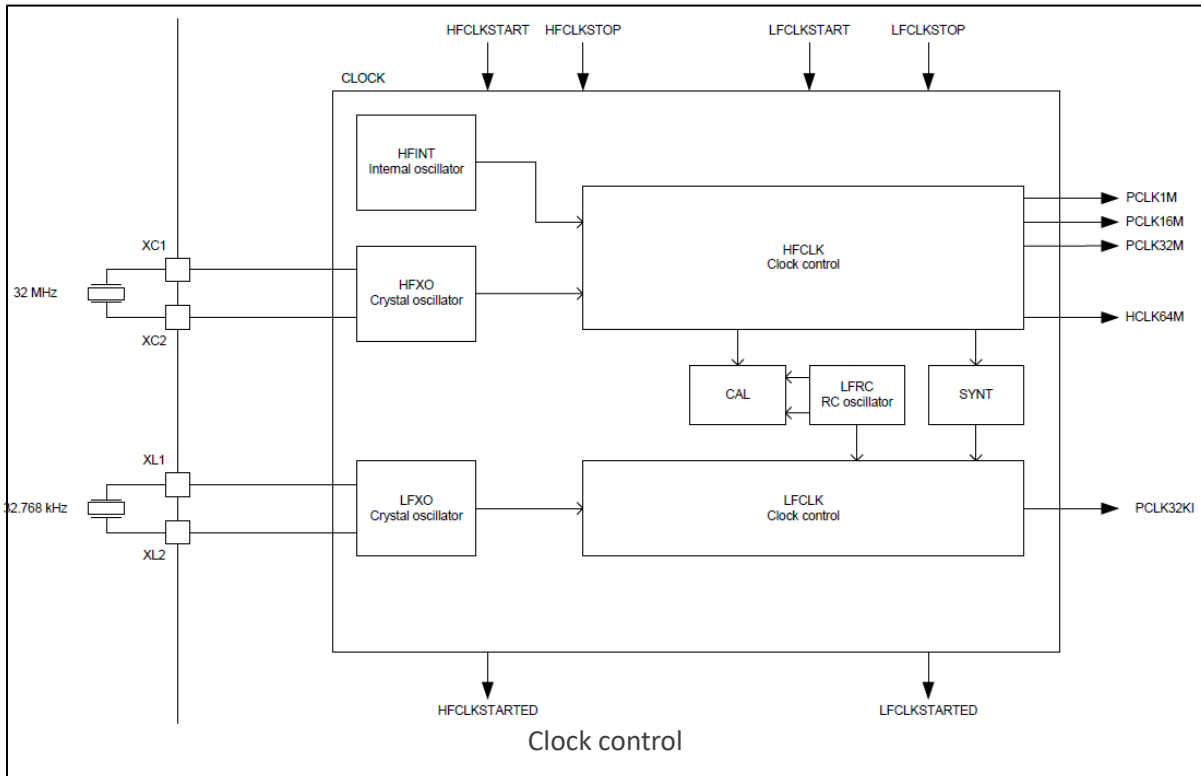
3.2 32.768KHz Crystal Oscillator

The BoT-nLE521 external 32.768KHz Crystal does not required for BLE mode

If you choose to use an internal 32.768kHz oscillator, an average of 10uA of current is consumed compared to an external crystal.

The ANT specification requires ± 50 ppm accuracy for a 32.768kHz clock. The internal 32.768kHz oscillator may not meet specifications.

BoT-nLE521 F/W does not yet support ANT Mode.



Circuit diagram of the 32.768 kHz crystal oscillator

The load capacitance (CL) is the total capacitance seen by the crystal across its terminals and is given by:

$$C_L = \frac{C1' \cdot C2'}{C1' + C2'}$$

$$C1' = C1 + C_{pcb1} + C_{pin}$$

$$C2' = C2 + C_{pcb2} + C_{pin}$$

C1 and C2 are ceramic SMD capacitors connected between each crystal terminal and ground. Cpcb1 and Cpcb2 are stray capacitances on the PCB.

▪ 32.768 kHz RC oscillator (LFRC)

Symbol	Description	Min.	Typ.	Max.	Units
$f_{\text{NOM_LFRC}}$	Nominal frequency		32.768		kHz
$f_{\text{TOL_LFRC}}$	Frequency tolerance		± 2		%
$f_{\text{TOL_CAL_LFRC}}$	Frequency tolerance for LFRC after calibration		± 500		ppm

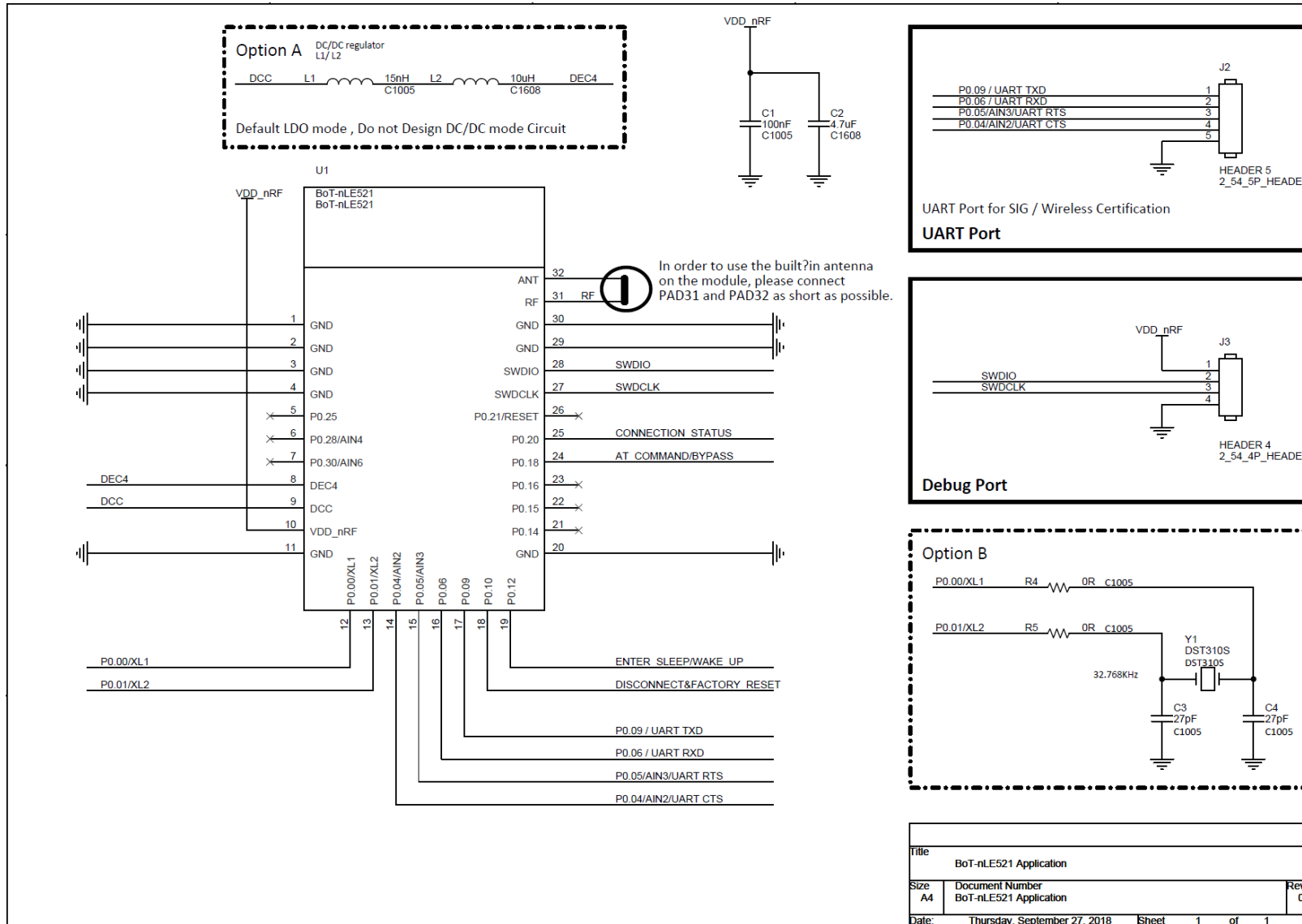
▪ 32.768 kHz crystal oscillator (LFXO)

Symbol	Description	Min.	Typ.	Max.	Units
$f_{\text{NOM_LFXO}}$	Crystal frequency		32.768		kHz
$f_{\text{TOL_LFXO_BLE}}$	Frequency tolerance requirement for BLE stack		± 250		ppm
$f_{\text{TOL_LFXO_ANT}}$	Frequency tolerance requirement for ANT stack		± 50		ppm
$C_{\text{L_LFXO}}$	Load capacitance			12.5	pF
$C_{\text{O_LFXO}}$	Shunt capacitance			2	pF
$R_{\text{S_LFXO}}$	Equivalent series resistance			100	kohm
$P_{\text{D_LFXO}}$	Drive level			1	uW
C_{pin}	Input capacitance on XL1 and XL2 pads		4		pF

DATASHEET

BoT-nLE512

4. Application Schematic



5. Antenna

5.1 Antenna Layout Guide

